UC3176 UC3177

UNITRODE

Full Bridge Power Amplifier

FEATURES

- Dual Power Operational Amplifiers
- ±2A Output Current Guaranteed
- Precision Current Sense Amplifier
- Two Supply Monitoring Inputs
- Parking Function and Under-Voltage Lockout
- Safe Operating Area Protection
- 3V to 35V Operation

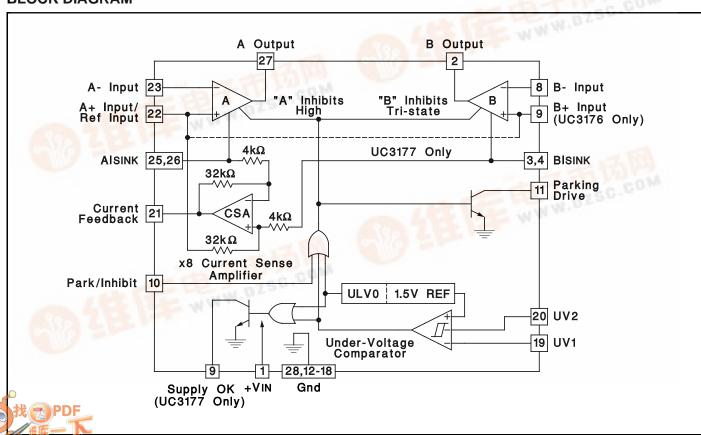
DESCRIPTION

The UC3176/7 family of full bridge power amplifiers is rated for a continuous output current of 2A. Intended for use in demanding servo applications such as disk head positioning, the onboard current sense amplifier can be used to obtain precision control of load current, or where voltage mode drive is required, a standard voltage feedback scheme can be used. Output stage protection includes foldback current limiting and thermal shutdown, resulting in a very rugged device.

Auxiliary functions on this device include a dual input under-voltage comparator that can be programmed to respond to low voltage conditions on two independent supplies. In response to an under-voltage condition the power Op-Amps are inhibited and a high current, 100mA, open collector drive output is activated. A separate Park/Inhibit command input.

The devices are operational over a 3V to 35V supply range. Internal under-voltage lockout provides predictable power-up and power-down characteristics.

BLOCK DIAGRAM



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ABSOLUTE MAXIMUM RATINGS (Note 1)

Input Supply voltage, (+VIN)
Park/Inhibit, UV1 and UV2 inputs (zener clamped)
Maximum forced voltage0.3V to 10V
Maximum forced current±10mA
Other Input Voltages0.3V to +VIN
Alsınk and Blsınk Voltages0.3V to 6V
Open Collector Output Voltages 40V
A and B Output Currents (Continuous)
Source Internally Limited
Sink
Total Supply Current (Continuous)4A
Parking Drive Output Current (Continuous) 200mA
Supply OK Output Current, UC3177 (Continuous) 30mA
Operating Junction Temperature55°C to +150°C
Power Dissipation at TC = +75°C
QP package 4W
Storage Temperature65°C to +150°C
Note 1: Unless otherwise indicated, voltages are reference to ground and currents are positive into, negative out of, the

THERMAL DATA

specified terminals.

QP package:

Thermal Resistance Junction to Leads, θJL 15°C/W Thermal Resistance Junction to Ambient, θJA 50°C/W

CONNECTION DIAGRAM

PLCC-28 (Top View) QP Package

/	4 3	2	1 2	8 27	26
5			$\bigcup_{i=1}^{n}$		25
6					24
[7					23
8					22
9					21
10					20
[11	12 13	3 14	15 1	6 17	19 18

PACKAGE PIN FUNC	TION
FUNCTION	PIN
+VIN	1
B Output	2
BISINK(Sense)	3
BISINK	4
N/C	5-7
B- Input	8
*	9
Park/Inhibit	10
Parking Drive	11
Gnd (Heat Flow Pins)	12-18
UV1	19
UV2	20
Current Feedback	21
A+ Input	22
A- Input	23
N/C	24
Alsink	25
Alsınk(Sense)	26
A Output	27
Gnd	28
*Pin 9: UC3176, B+ Inp	out

*Pin 9: UC3176, B+ Input UC3177, Supply OK

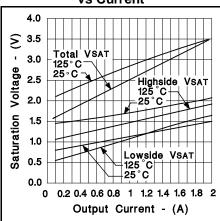
$\textbf{ELECTRICAL CHARACTERISTICS:} \quad \text{Unless otherwise stated, specifications hold for TA = 0 to 70°C, +VIN = 12V, TA = TJ.}$

PARAMETER	TEST CONDITIONS		TYP.	MAX.	UNITS
Input Supply					
Supply Current	+VIN = 12V		18	25	mA
	+VIN = 35V		21	30	mA
UVOL Threshold	+VIN low to high		2.8	3.0	V
	Threshold Hysteresis		220	300	mV
Power, Amplifier, A and B					
Input Offset Voltage	VCM = 6V, VOUT = 6V			8	mV
Input Bias Current	Vcm = 6V, Except A+ Input		-100		nA
Input Bias Current at A+/Reference Input	(A+/Ref - BISINK)/36kohms; TJ = 25°C		28	35	μΑ/V
Input Offset Current B Amp (UC3176 Only)	Vcm = 6V			200	nA
CMRR	Vcm = 1 to 33V, +Vin =35V, Vout = 6V	70	100		dB
PSRR	+VIN = 5 to 35V, VCM = 2.5V	70	100		dB
Large Signal Voltage Gain	VOUT = 3V, w/IOUT = 1A to VOUT = 9V, w/IOUT = -1A	1.5	4		V/mV
Thermal Feedback	+VIN = 20V, Pd = 20W at opposite output		25	200	μV/W
Saturation Voltage	IOUT = -2A, High Side, TJ = 25°		1.9		V
	Clout = 2A, Low Side, T _J = 25°C		1.6		V
	Total VsAT at 2A, TJ = 25°C		3.5	3.7	V
Unity Gain Bandwidth			1		MHz
Slew Rate			1		V/μs
Differential IOUT Sense Error Current	IOUT(A) = -IOUT(B), /IOUT/- /AISINK - BISINK/				
in Bridge Configuration	IOUT ≤200mA		3.0	6.0	mA
	IOUT ≤ 2A		5.0	10	mA
High Side Current Limiting	=VIN - VOUT < 12V		-2.7	-2.0	Α

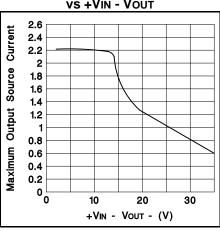
ELECTRICAL CHARACTERISTICS: Unless otherwise stated, specifications hold for Ta = 0 to 70°C, +VIN = 12V, Ta = TJ.

PARAMETER	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Current Sense Amplifier					
Input Offset Voltage	Vcm = 0V, A+/Ref at 6V			3	mV
	Ref = 2V to 20V, +VIN = 35, change with Ref				
	input voltage			600	μV/V
Thermal Gradient Sensitivity	+VIN = 20V, Ref = 10V Pd = 20W @ A or B				
	output		5.0	75	μV/W
PSRR	Ref = $2.5V$, $+VIN = 5$ to $35V$	70	100		dB
Gain	/Alsınk - Blsınk/ ≤ 0.5V	7.8	8	8.1	V/V
Slew Rate			2		V/μS
3dB Bandwidth			1		MHz
Max Output Current	ISOURCE = +VIN - VOUT = 0.5V	2.5	3.5		mA
Output Saturation Voltage	ISOURCE = 1.5mA, High Side		0.15	0.30	V
	ISINK = 5mA, Low Side		1.4	1.7	V
Under-Voltage Comparator					
Threshold Voltage	Low to High, other input at 5V	1.44	1.50	1.56	V
	Threshold Hysteresis	50	70	80	mV
Input Current	Input = 2V, other input at 5V	-2	05		μΑ
Supply OK V _{SAT} (UC3177 Only)	IOUT = 5mA			0.45	V
Supply OK Leakage (UC3177 Only)	Vout = 35V			5	μΑ
Park/Inhibit					
Park/Inhibit Thl'd		1.1	1.3	1.7	V
Park/Inhibit Input Current	At threshold		60	100	μΑ
Parking Drive Saturation Voltage	I _{OUT} = 100mA		0.3	0.7	V
Parking Drive Leakage	V _{OUT} = 35V			15	μΑ
Thermal Shutdown					_
Shutdown Temperature			165		°C

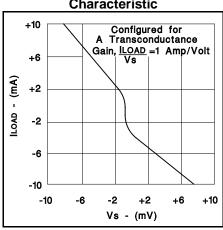
Output Saturation Voltage vs Current



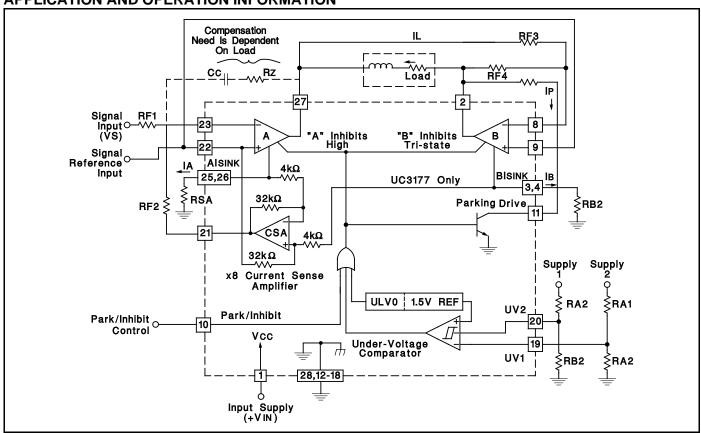
Maximum Source Current vs +VIN - Vout



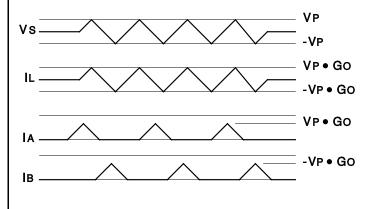
Crossover Current Error Characteristic



APPLICATION AND OPERATION INFORMATION



WAVEFORMS FOR ABOVE APPLICATION



DESIGN EQUATIONS

Transconductance (Go) =
$$\frac{IL}{Vs} = \frac{RF2}{RF1} \times \left(\frac{1}{8Rs}\right)$$

with: RSA = RSB and RF3 = RF4

Parking Current (IP) =
$$\frac{V_{IN} - 1.5}{R_P + R_L}$$

where: RL = load resistance

Under-Voltage Thresholds, at Supplies High to Low Threshold, (VLH) = 1.425 (RA + RB)/RBLow to High Threshold, (VHL) = 1.5 (RA + RB)/RB

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